

- ✎ L21: (217123) source near 9 drain
- ✎ L22: (4248867) 1 source near drain source adj drain drain adj source s/d 6
- ✎ L23: (780) 20 with 21 with 3
- ✎ L24: (6489156) plug electrode contact wa
- ✎ L25: (363) 23 with 24
- ✎ L26: (11590926) form \$4
- ✎ L27: (226) 25 with 26
- ✎ L28: (561789) resistor
- ✎ L29: (91436) resistive adj (element device film layer)
- ✎ L30: (32) 27 with 28
- ✎ L31: (41921) resistive adj2 (element device film layer)
- ✎ L32: (575277) 28 29
- ✎ L33: (582378) 28 31
- ✎ L34: (108522) 24 near 4 33
- ✎ L35: (14) 27 with 34
- ✎ L36: (142270) 24 near 9 33
- ✎ L37: (24) 27 with 36
- ✎ L38: (3) 08/028789
- ✎ L40: (15) "JOYCE, CHRISTOPHER".in.
- ✎ L39: (23) "ROBINSON, MURRAY".in.
- ✎ L41: (29) 39 40
- ✎ L42: (5) 41 and 28
- ✎ L44: (4) "4233815".pn.
- ✎ L43: (3) "4233615".pn.
- ✎ L45: (20) 37 and 28

S7 and 28

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	U	I	Inventor	Document ID	Issu	P	Title	Current	Current I	Retrie	S	C	P	S	Image	Do P
1	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	R. Takemoto	US 4233615 A	1980	17	Semiconductor integrated circuit dev	257/27	257/538		<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	US 4233615
2	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	JOYCE CHHRI	EP 545363 A1	1993	2	Integrated circuit fabrication process	257/E213			<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	EP 545363
3	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	Lee, Sang-Ji	US 20040087031 A1	2004	11	METHOD OF FABRICATING A SEMICONDUCTOR	438/23	257/E27.01		<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	US 20040
4	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	Lee, Sang-Ji	US 6869839 B2	2005	10	Method of fabricating a semiconductor	438/23	438/305		<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	US 6869839
5	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	Bae, Ki-Soo	US 6825081 B2	2004	6	Semiconductor memory device and me	438/38	438/239		<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	US 6825081
6	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	Kinoshita, Y	US 6025219 A	2000	17	Method of manufacturing a semiconductor	438/20	257/E21.6		<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	US 6025219
7	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	Shimada, T	US 5691787 A	1997	11	Active matrix type LCD having short res	348/40	257/59		<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	US 5691787
8	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	Hakagawa, S	US 5650634 A	1997	16	Active-matrix device having silicide thi	349/13	349/147		<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	US 5650634
9	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	Kikuchi, To	US 5321650 A	1994	37	BICMOS semiconductor memory device	365/177	257/278		<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	US 5321650
10	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	Suzuki, Yas	US 5310695 A	1994	07	Interconnect structure in semiconductor	438/38	257/E21.5		<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	<input checked="" type="checkbox"/>	US 5310695